NSN 5961-01-349-0232

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-349-0232 **Inclosure Material:** Glass **Overall Length:** Between 0.140 inches and 0.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.055 inches and 0.130 inches **Function For Which Designed:** Rectifier **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 720.0 nonrepetitive peak reverse voltage and 600.0 working peak reverse voltage **Current Rating Per Characteristic:** 150.00 milliamperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Item is enclosed in a u shaped insulating tube; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No